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10/509,463	09/27/2004	Kazuyoshi Honda	10873.1171USWO	2211
53148 7590 12/10/2008 HAMRE, SCHUMANN, MUELLER & LARSON P.C. P.O. BOX 2902-0902 MINNEAPOLIS, MN 55402				
EXAMINER WIECZOREK, MICHAEL P				
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**Please find below and/or attached an Office communication concerning this application or proceeding.**

The time period for reply, if any, is set in the attached communication.

### Office Action Summary

**Application No.**

10/509,463

**Applicant(s)**

HONDA ET AL.

**Examiner**

Michael Wieczorek

**Art Unit**

1792

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --  
**Period for Reply**

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

**Status**

- 1) ☒ Responsive to communication(s) filed on 22 October 2008.
- 2a) ☐ This action is **FINAL**. 2b) ☒ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

**Disposition of Claims**

- 4) ☒ Claim(s) 5 and 7-11 is/are pending in the application.
- 4a) Of the above claim(s) 10 and 11 is/are withdrawn from consideration.
- 5) ☐ Claim(s) \_\_\_\_\_ is/are allowed.
- 6) ☒ Claim(s) 5 and 7-9 is/are rejected.
- 7) ☐ Claim(s) \_\_\_\_\_ is/are objected to.
- 8) ☐ Claim(s) \_\_\_\_\_ are subject to restriction and/or election requirement.

**Application Papers**

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☐ The drawing(s) filed on \_\_\_\_\_ is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.  
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).  
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

**Priority under 35 U.S.C. § 119**

- 12) ☒ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☒ All b) ☐ Some \* c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
  2. ☐ Certified copies of the priority documents have been received in Application No. \_\_\_\_\_.
  3. ☒ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

\* See the attached detailed Office action for a list of the certified copies not received.

**Attachment(s)**

- 1) ☒ Notice of References Cited (PTO-892)
- 2) ☐ Notice of Draftperson's Patent Drawing Review (PTO-948)
- 3) ☐ Information Disclosure Statement(s) (PTO/SB/08)  
Paper No(s)/Mail Date: \_\_\_\_\_
- 4) ☐ Interview Summary (PTO-413)  
Paper No(s)/Mail Date: \_\_\_\_\_
- 5) ☐ Notice of Informal Patent Application
- 6) ☐ Other: \_\_\_\_\_

## **DETAILED ACTION**

### ***Continued Examination Under 37 CFR 1.114***

1. A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(c), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(c) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on October 22, 2008 has been entered.

### ***Status of Application***

2. By amendment filed October 22, 2008, claim 5 has been amended. Claims 5, 7-11 are currently pending. The applicant had received a first action on the merits for the originally presented invention. This invention has been constructively elected by original presentation for prosecution on the merits. However, claims 10-11 were objected to and should have been withdrawn from consideration as being directed to a non-elected invention. See 37 CFR 1.142(b) and MPEP § 821.03. Claims 5, 7-9 of the present case relate to the elected apparatus invention while claims 10-11 relate to the non-elected method invention. Lack of unity was established between the apparatus invention and the method invention in a first non-final action dated April 1, 2008. In a reply to this first action on the merits dated June 24, 2008, applicant did not argue the lack of unity and instead added new claims 10-11 disclosing a method invention. In the Final Rejection dated July 22, 2008, claims 10 and 11 were withdrawn from consideration as discussed above, as being related to a non-elected invention. Claims 10 and 11 are still present within the claims and have not been withdrawn by the applicant since they have a status identifier of

"Previously Presented". Since Lack of Unity has been established between the apparatus invention and method invention of the originally presented claims and applicant has not successfully traversed the Lack of Unity between the two inventions the Examiner believes that the status identifier for claims 10 and 11 is in error and should have been presented as "Withdrawn". Thus claims 10 and 11 have been withdrawn from consideration.

### ***Response to Arguments***

3. Applicant's arguments, see pages 4 through, filed October 22, 2008, with respect to the rejection(s) of claim(s) 5, 7 through 9 under 103(a) have been fully considered and are persuasive in that the prior presented fails to provide adequate motivation for wanting to ionize the resistance heated metals of Yano (U.S. Patent Publication No. 2002/0001733). Therefore, the rejection has been withdrawn. However, upon further consideration, a new grounds of rejection is made in view of new prior art necessitated by amendments made to the claims.

### ***Claim Interpretation – 112 Sixth Paragraph***

4. Within claim 1 of the application applicant has invoked 112 sixth paragraph with the term "means for supporting the supporting base". Based on what is disclosed within the specification, the supporting base 20 is supporting by rollers (roller 10, guide roll 16, ect.) (Page 4 Lines 15-25, Figure 1). Thus the term "means for supporting" is interpreted to mean a continuous web support type structure.

***Claim Rejections - 35 USC § 103***

5. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

6. The factual inquiries set forth in *Graham v. John Deere Co.*, 383 U.S. 1, 148 USPQ 459 (1966), that are applied for establishing a background for determining obviousness under 35 U.S.C. 103(a) are summarized as follows:

1. Determining the scope and contents of the prior art.
2. Ascertaining the differences between the prior art and the claims at issue.
3. Resolving the level of ordinary skill in the pertinent art.
4. Considering objective evidence present in the application indicating obviousness or nonobviousness.

7. Claims 5, 7 and 9 are rejected under 35 U.S.C. 103(a) as being unpatentable over DeLozanne (U.S. Patent # 5,004,721) in view of Higuchi (U.S. Patent # 5,079,224) and Shioya et al (U.S. Patent # 5,017,550). (Suzuki et al (U.S. Patent # 4,622,919) is cited as evidence regarding electron beam apparatus.)

DeLozanne teaches an apparatus for forming oxide superconductor thin films comprising a vacuum container which comprises a first vacuum chamber 18 and a second vacuum chamber 12 (Column 2 Lines 33-34, Column 3 Lines 46-51 and Figure 1).

The apparatus further comprises a supporting base in the form of substrate 20 and a means for supporting the substrate in the form of substrate mount 21. As is taught by Figure 1 of the reference, both the substrate 20 and substrate mount 21 are inside the vacuum chamber 18,

thus the reference teaches a means for supporting the supporting base in an inner portion of the vacuum container or chamber. (Column 3 Lines 46-51 and Figure 1)

DeLozanne further teaches a resistance heating evaporation source in the form of resistively-heated boat 14b which contains a second thin film material in the form of barium metal and as is taught by Figure 1 of the reference the resistance heating evaporation source 14b is arranged within the vacuum container so as to face the substrate 20, which is the surface to be vapor-deposited (Column 4 Lines 1-3 and Figure 1).

DeLozanne further teaches a electron beam source 14a which is used for the electron beam evaporation of a first thin film material in the form of yttrium metal and as is taught by Figure 1 of the reference the source 14a is arranged in the vacuum container so as to face the substrate 20 (Column 4 Lines 1-3 and Figure 1).

DeLozanne does not explicitly teach an electron beam source to heat and evaporate the first thin material but this component would be an inherent feature of the taught electron beam source 14a as envisaged by Suzuki et al. Suzuki et al teaches a film forming apparatus comprising a vacuum chamber used to form a film by electron beam evaporation (Abstract and Column 2 Lines 15-18 of Suzuki et al). The electron beam evaporation component of Suzuki et al comprises an evaporator 6 which contains a deposition material A, which is analogous to the first thin film material of DeLozanne and an electron beam source or electron gun 6a which heats and evaporates the deposition material A (Column 3 Lines 1-4 and Figure 1 of Suzuki et al). Thus based on the teachings of Suzuki et al one of ordinary skill in the art would know that the electron beam evaporation source 14a of DeLozanne would inherently comprise an electron beam source to heat and evaporate the material contained in the source 14a.

Though DeLozanne teaches a means for supporting a supporting base or substrate it does not teach that the means for support are the same as the continuous web supporting means used to support the substrate as disclosed in the specification of the present case (Figure 1 of the present case).

Shioya et al teaches a coating apparatus for forming a continuous oxide superconductor thin film (Abstract, Column 1 Lines 59-61, and Figure 4). The taught apparatus comprises a elongate substrate 21 supported by rollers (supply roll 26 and take-up reel 27) within a vacuum chamber 25 (Column 5 Lines 36-50, Figure 4). Thus Shioya et al teaches a continuous web supporting means supporting a substrate within a vacuum chamber.

At the time the present invention was made it would have been obvious to one of ordinary skill in the art to have within a thin film forming apparatus a supporting means for a supporting base or substrate in the form of a continuous web type support. By substituting the substrate mount 21 of DeLozanne with the continuous web support of Shioya et al the apparatus of DeLozanne can be used to form a continuous oxide superconductor thin film.

Though DeLozanne in view of Shioya et al as envisaged by Suzuki et al teaches all the structural components of the disclosed apparatus of claim 5 it does not teach the arrangement of the components where the path along which the electron beam travels intersects with a line segment connecting the resistance heating evaporation source with the surface to be vapor deposited as it travels to the electron evaporation source.

Higuchi teaches an apparatus for forming a superconductive thin film comprising barium yttrium, copper and oxygen (Column 3 Lines 13-18) which is the type of thin film being produced by the apparatus of DeLozanne. The apparatus of Higuchi comprises a resistance

heating source containing barium (Column 3 Lines 19-36) which is the same resistance heated material of DeLozanne. Higuchi teaches that the barium metal material is heated and evaporated and the evaporated metal passes through an electron beam where it is ionized (Column 4 Lines 56-68). Higuchi teaches that by ionizing the metal to be deposited a film is formed with good crystallization and adhesion (Column 1 Lines 30-50).

Thus at the time the present invention was made it would have been obvious to arrange the electron beam source and the resistance heating evaporation source in a manner where the path along which the electron beam travels intersects with a line segment connecting the resistance heating evaporation source with the surface to be vapor deposited as it travels to the electron evaporation source. By arranging the electron beam source of source 14a of DeLozanne as envisaged by Suzuki et al in such a manner such that the electron beam intersects with a line segment connecting the resistance heating evaporation source 14b with substrate 20 the barium evaporated from the source 14b can be ionized by the electron beam and thus produce a thin film which has good crystallization and adhesion as taught by Higuchi. Since it is known in the art that by ionizing barium with an electron beam prior to deposition produces a superior thin film one of ordinary skill in the art would be motivated to ionize the barium and this can be accomplished by using the electron beam source of DeLozanne as envisaged by Suzuki et al.

As for claim 7, DeLozanne teaches that the apparatus comprises a glass nozzle 28 which sprays a reactive gas in the form of oxygen onto the substrate 20 (Column 3 Lines 56-63 and Figure 1) thus DeLozanne teaches that the nozzle 28 introduces a reactive gas in a portion on the surface to be vapor-deposited in which the thin film is to be formed.



As for claim 9, the specification of the present case defines “substantially on the same plane” when the electron beam can pass through the vapor stream of the second thin film material that is emanating from the resistance heating source (Page 5 Lines 10-15 of the specification of the present case). As was discussed in the claim 5 rejection, based on the teachings of DeLozanne as envisage by Suzuki et al in view of Higuchi and Shioya et al the electron beam source and the resistance heating source are arranged so that the electron beam emanated from the electron beam source intersects a line segment connecting the resistance heating source with the surface to be vapor deposited thereby allowing the electron beam to pass through the vapor stream of the second thin film material thus ionizing it. For this reason it can be considered that the electron beam evaporation source, the electron beam source and the resistance heating evaporation source of the apparatus taught by DeLozanne as envisage by Suzuki et al in view of Higuchi and Shioya et al are substantially on the same plane. Thus claim 9 is rejected.

8. Claim 8 is rejected under 35 U.S.C. 103(a) as being unpatentable over DeLozanne in view of Higuchi and Shioya et al as applied to claim 5 above, and further in view of Suzuki et al.

Neither DeLozanne, Shioya et al or Higuchi teach that the apparatus comprises a bias device for applying a bias voltage to the surface to be vapor-deposited.

The apparatus of Suzuki et al comprising a bias device in the form of a bias voltage source 14 which is connected to, thus supplying bias voltage, a surface to be vapor deposited in the form of substrate T. Suzuki et al teaches that the bias voltage source 14 is present to accelerate the ionized vapor toward the substrate T for deposition. In other words the bias

voltage supplied to substrate T attracts the ionized vapor to the surface of substrate T. (Column 4 Lines 9-16, Figure 2)

Therefore, it would have been obvious to one of ordinary skill in the art at the time the present invention was made to add the bias device of Suzuki et al to the apparatus of DeLozanne in view of Higuchi and Shioya et al so that a bias voltage could be supplied to the deposition surface thus causing more attraction between the surface to be vapor deposited and the ionized thin film vapor materials.

### ***Conclusion***

Claims 5, 7 through 9 have been rejected. Claims 10 and 11 have been withdrawn from consideration as being a non-elected invention.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Michael Wieczorek whose telephone number is (571)270-5341. The examiner can normally be reached on Monday through Friday; 7:30 AM to 5:00 PM (EST).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Michael Cleveland can be reached on (571)272-1418. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

/MPW/

/Michael Wieczorek/  
Examiner, Art Unit 1792

/Michael Cleveland/

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